TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

# SSM3K35FS

- High-Speed Switching Applications
- Analog Switch Applications
- 1.2-V drive
- Low ON-resistance:  $R_{on}$  = 20  $\Omega$  (max) (@V<sub>GS</sub> = 1.2 V)
  - :  $R_{on}$  = 8  $\Omega$  (max) (@V<sub>GS</sub> = 1.5 V)
  - :  $R_{on}$  = 4  $\Omega$  (max) (@V<sub>GS</sub> = 2.5 V)
  - :  $R_{on}$  = 3  $\Omega$  (max) (@V<sub>GS</sub> = 4.0 V)

#### Absolute Maximum Ratings (Ta = 25°C)

| Characteristics         |       | Symbol           | Rating     | Unit |  |
|-------------------------|-------|------------------|------------|------|--|
| Drain-source voltage    |       | V <sub>DSS</sub> | 20         | V    |  |
| Gate-source voltage     |       | V <sub>GSS</sub> | ±10        | V    |  |
| Drain current           | DC    | ۱ <sub>D</sub>   | 180        | mA   |  |
|                         | Pulse | I <sub>DP</sub>  | 360        |      |  |
| Drain power dissipation |       | PD               | 100        | mW   |  |
| Channel temperature     |       | T <sub>ch</sub>  | 150        | °C   |  |
| Storage temperature     |       | T <sub>stg</sub> | –55 to 150 | °C   |  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba

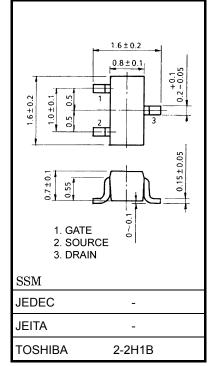
Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Electrical Characteristics (Ta = 25°C)**

| Chara   | acteristics          | Symbol  | Test Condition   |          | Min | Тур. | Max  | Unit |
|---|----------------------|---|--|----------|-----|------|------|------|
| Gate leakage cur                                | rent                 | I <sub>GSS</sub>                                      | $V_{GS}=\pm 10~V,~V_{DS}=0V$                                   |          | _   | _    | ±10  | μA   |
| Drain-source bre                                | akdown voltage       | V (BR) DSS  | $I_D = 0.1 \text{ mA}, V_{GS} = 0 \text{V}$                    |          | 20  |      | _    | V    |
| Drain cutoff curre                              | nt                   | I <sub>DSS</sub>                                      | $V_{DS}=20~V,~V_{GS}=0V$                                       |          | _   |      | 1    | μA   |
| Gate threshold vo                               | oltage               | V <sub>th</sub>                                       | $V_{DS} = 3 V, I_D = 1 mA$                                     |          | 0.4 |      | 1.0  | V    |
| Forward transfer                                | admittance           | Y <sub>fs</sub>                                       | $V_{DS} = 3 \text{ V}, \text{ I}_{D} = 50 \text{ mA}$          | (Note 1) | 115 |      | _    | mS   |
| Drain–source ON-resistance                      |                      | $I_{D} = 50 \text{ mA}, V_{GS} = 4 \text{ V}$         | (Note 1)   | _        | 1.5 | 3    | Ω    |      |
|   | R <sub>DS (ON)</sub> | $I_D = 50 \text{ mA}, \text{ V}_{GS} = 2.5 \text{ V}$ | (Note 1)   | _        | 2   | 4    |      |      |
|   |                      | $I_{D} = 5 \text{ mA}, V_{GS} = 1.5 \text{ V}$        | (Note 1)   | _        | 3   | 8    |      |      |
|   |                      | $I_D = 5 \text{ mA}, V_{GS} = 1.2 \text{ V}$          | (Note 1)   | _        | 5   | 20   |      |      |
| Input capacitance                               | 9                    | C <sub>iss</sub>                                      |  |          |     | 9.5  |      |      |
| Reverse transfer capacitance Output capacitance |                      | C <sub>rss</sub>                                      | $V_{DS} = 3 \text{ V}, V_{GS} = 0 \text{V}, f = 1 \text{ MHz}$ |          | _   | 4.1  |      | pF   |
|   |                      | C <sub>oss</sub>                                      |  | _        | 9.5 |      |      |      |
| Switching time                                  | Turn-on time         | t <sub>on</sub>                                       | $V_{DD} = 3 V, I_D = 50 mA,$                                   |          | _   | 115  |      |      |
|   | Turn-off time        | t <sub>off</sub>                                      | V <sub>GS</sub> = 0 to 2.5 V                                   |          | _   | 300  |      | ns   |
| Drain-source for                                | ward voltage         | V <sub>DSF</sub>                                      | I <sub>D</sub> = - 180 mA, V <sub>GS</sub> = 0V                | (Note 1) | _   | -0.9 | -1.2 | V    |

Note 1: Pulse test

Start of commercial production 2008-02



Weight: 2.4 mg (typ.)

Unit: mm

## TOSHIBA

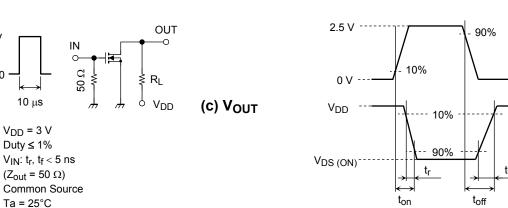
### Switching Time Test Circuit

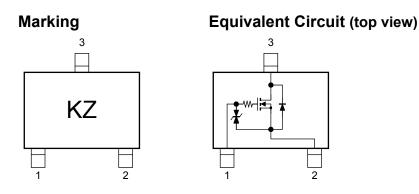
(a) Test Circuit

2.5 V

0

(b) V<sub>IN</sub>





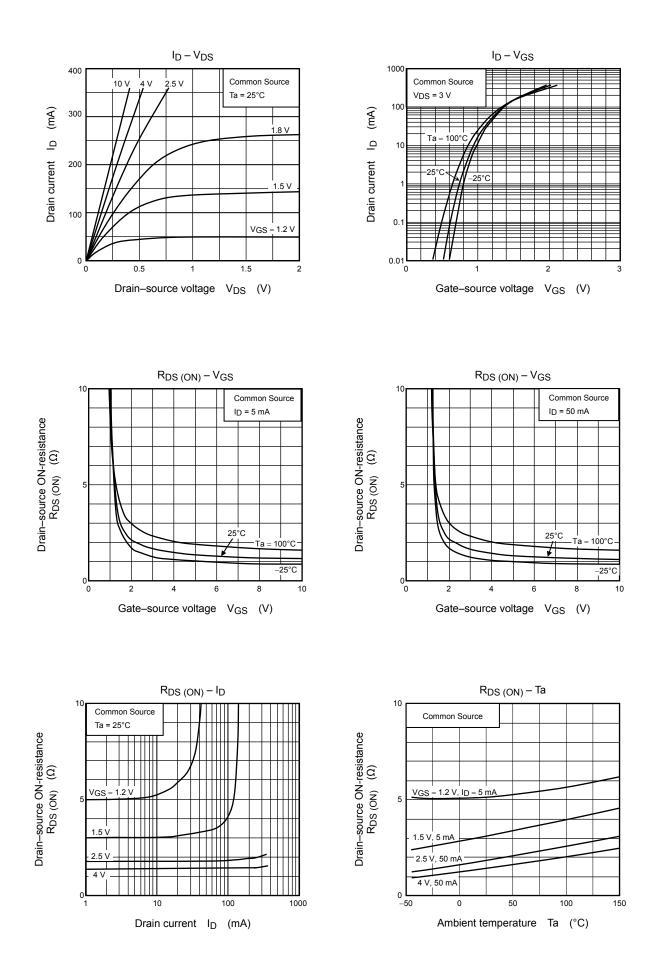
#### **Usage Considerations**

Let Vth be the voltage applied between gate and source that causes the drain current (ID) to below (1 mA for the SSM3K35FS). Then, for normal switching operation, V<sub>GS(on)</sub> must be higher than V<sub>th</sub>, and V<sub>GS(off)</sub> must be lower than V<sub>th.</sub> This relationship can be expressed as: V<sub>GS(off)</sub> < V<sub>th</sub> < V<sub>GS(on)</sub>. Take this into consideration when using the device.

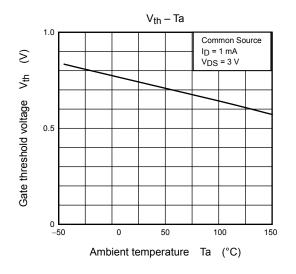
#### **Handling Precaution**

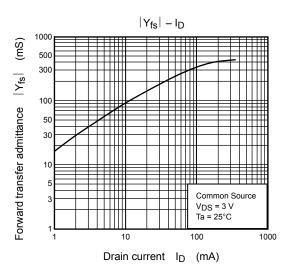
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

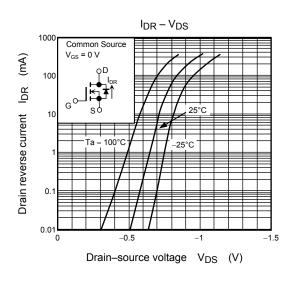
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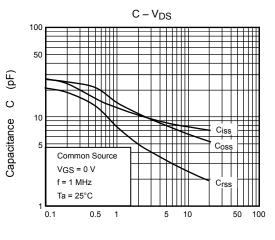


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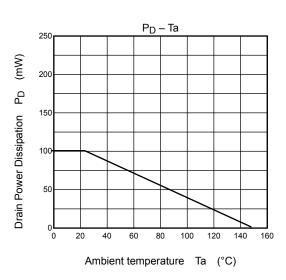


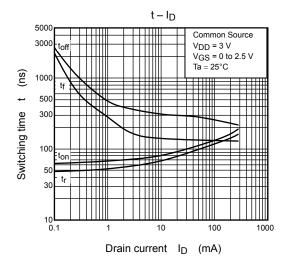












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